

1. General Description

The EM74HCS245 is an 8-bit transceiver with 3-state outputs and Schmitt-trigger inputs. The device features an output enable ($\overline{OE}$) and send/receive (DIR) for direction control. A HIGH on $\overline{OE}$ causes the outputs to assume a high-impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and Benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- High noise immunity
- CMOS low power dissipation
- Latch-up performance exceeds 250 mA
- Unlimited rise and fall times
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 3A exceeds 6000 V
 - CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V
- Multiple package options

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3. Ordering Information

Table 1. Ordering information

Type number	Package		
	Name	Description	Quantity
EM74HCS245D	SOP-20L	plastic small outline package; 20 leads; body width 7.5 mm	3000
EM74HCS245PW	TSSOP-20L	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	3000

4. Function Diagram

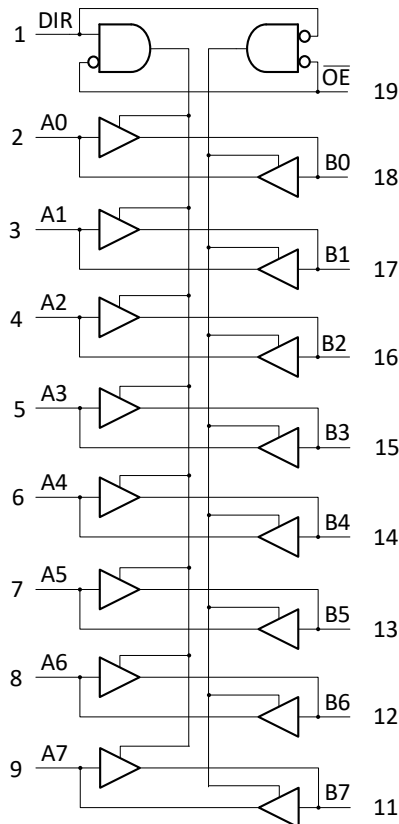


Fig. 1. Logic symbol

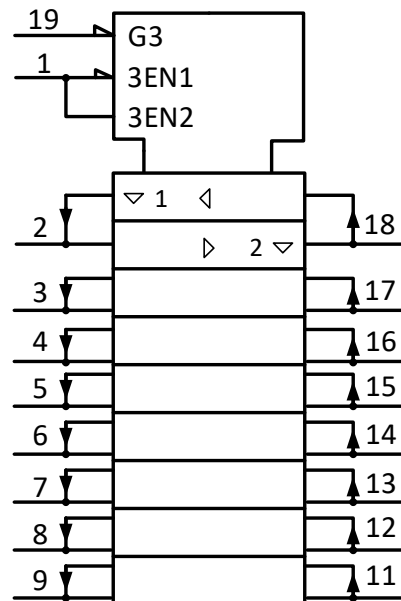
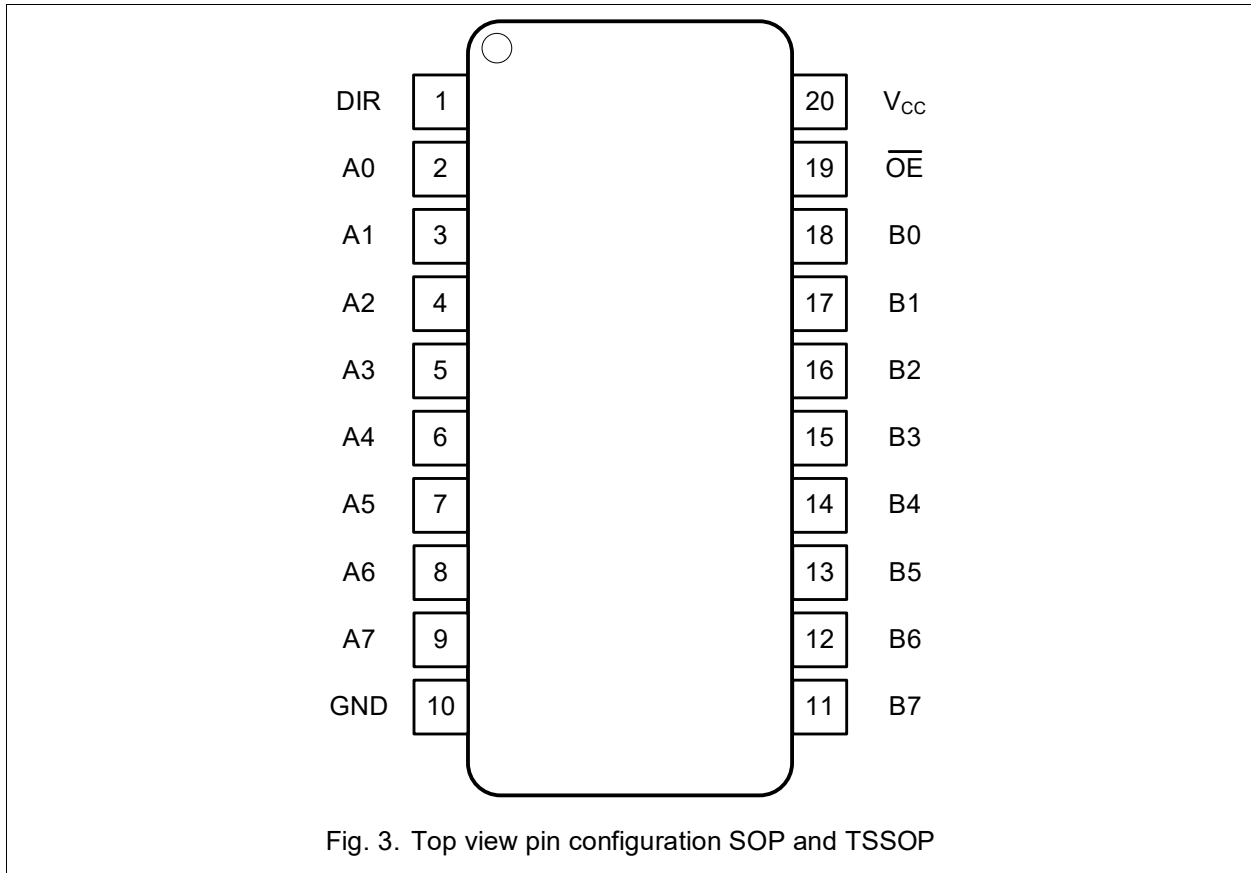


Fig. 2. IEC logic symbol

5. Pinning Information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
DIR	1	Direction control
A0, A1, A2, A3, A4, A5, A6, A7	2, 3, 4, 5, 6, 7, 8, 9	Data input/output
GND	10	Ground (0 V)
B7, B6, B5, B4, B3, B2, B1, B0	11, 12, 13, 14, 15, 16, 17, 18	Data input/output
$\overline{OE}$	19	Output enable input (active LOW)
V_{CC}	20	Supply voltage

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6. Functional Description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input		Input/output	
$\overline{OE}$	DIR	An	Bn
L	L	A = B	input
L	H	input	B = A
H	X	Z	Z

7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Table 4. Absolute Maximum Ratings

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	7.0	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ [1]		± 20	mA
I_{OK}	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ [1]		± 20	mA
I_O	output current	$V_O = -0.5\text{ V}$ to $(V_{CC} + 0.5\text{ V})$		± 25	mA
I_{CC}	supply current			50	mA
I_{GND}	ground current		-50		mA
P_{tot}	total power dissipation			500	mW
T_{stg}	storage temperature		-65	150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

Table 5. Recommended Operating Conditions

Symbol	Parameter	Conditions	EM74HCS245			Unit
			Min	Typ	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	V
V _I	input voltage		0		V _{CC}	V
V _O	output voltage		0		V _{CC}	V
T _{amb}	ambient temperature		-40		125	°C

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9. Static Characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V). Typical values measured at $T_{amb} = 25^{\circ}\text{C}$ (unless otherwise noted).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
V_{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}						
		$I_O = -20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$	1.9			1.9		V
		$I_O = -20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$	4.4			4.4		V
		$I_O = -20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$	5.9			5.9		V
		$I_O = -6.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$	3.84			3.7		V
		$I_O = -7.8\ \text{mA}; V_{CC} = 6.0\ \text{V}$	5.34			5.2		V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}						
		$I_O = 20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$			0.1		0.1	V
		$I_O = 20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$			0.1		0.1	V
		$I_O = 20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$			0.1		0.1	V
		$I_O = 6.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$			0.33		0.4	V
		$I_O = 7.8\ \text{mA}; V_{CC} = 6.0\ \text{V}$			0.33		0.4	V
I_I	input leakage current	$V_I = V_{CC}$ or GND ; $V_{CC} = 6.0\ \text{V}$			± 1		± 1	μA
I_{OZ}	OFF-state output current	$V_I = V_{T+}$ or $V_{T-}; V_{CC} = 6.0\ \text{V};$ $V_O = V_{CC}$ or GND			± 5		± 10	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND ; $I_O = 0\ \text{A};$ $V_{CC} = 6.0\ \text{V}$			20		40	μA
C_I	input capacitance			4.0				pF
$C_{I/O}$	Input/output capacitance			7.7				pF

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10. Dynamic Characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6. Typical values measured at $T_{amb} = 25^{\circ}\text{C}$ (unless otherwise noted).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
t_{pd}	propagation delay	An to Bn or Bn to An; see Fig. 4 [1]						
		$V_{CC} = 2.0\text{ V}$			35		40	ns
		$V_{CC} = 4.5\text{ V}$			20		25	ns
		$V_{CC} = 6.0\text{ V}$			15		20	ns
t_{en}	enable time	$\overline{OE}$ to An or Bn; see Fig. 5 [2]						
		$V_{CC} = 2.0\text{ V}$			35		40	ns
		$V_{CC} = 4.5\text{ V}$			20		25	ns
		$V_{CC} = 6.0\text{ V}$			15		20	ns
t_{dis}	disable time	$\overline{OE}$ to An or Bn; see Fig. 5 [3]						
		$V_{CC} = 2.0\text{ V}$			35		40	ns
		$V_{CC} = 4.5\text{ V}$			20		25	ns
		$V_{CC} = 6.0\text{ V}$			15		20	ns
t_t	transition time	see Fig. 4 [4]						
		$V_{CC} = 2.0\text{ V}$			9		11	ns
		$V_{CC} = 4.5\text{ V}$			6		8	ns
		$V_{CC} = 6.0\text{ V}$			4		5	ns
C_{PD}	power dissipation capacitance	per transceiver; $V_I = \text{GND to } V_{CC}$ [5]		18				pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[4] t_t is the same as t_{THL} and t_{TLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

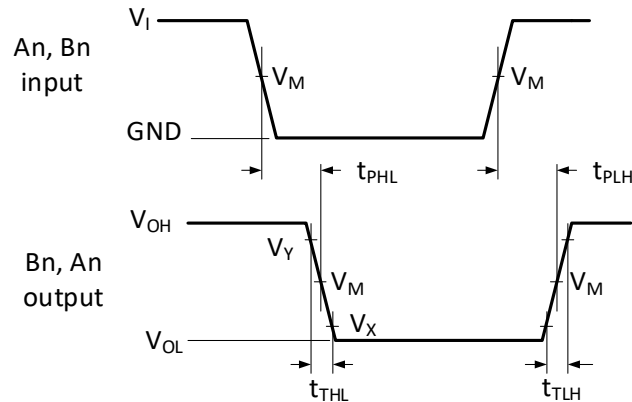
N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

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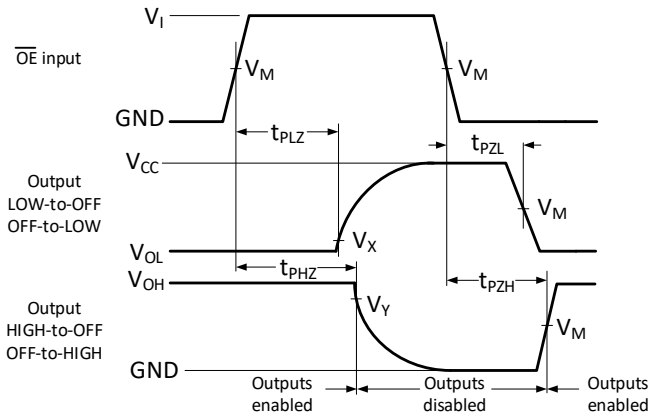
10.1. Waveforms and test circuit



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. Input (An, Bn) to output (Bn, An) propagation delays and output transition times



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

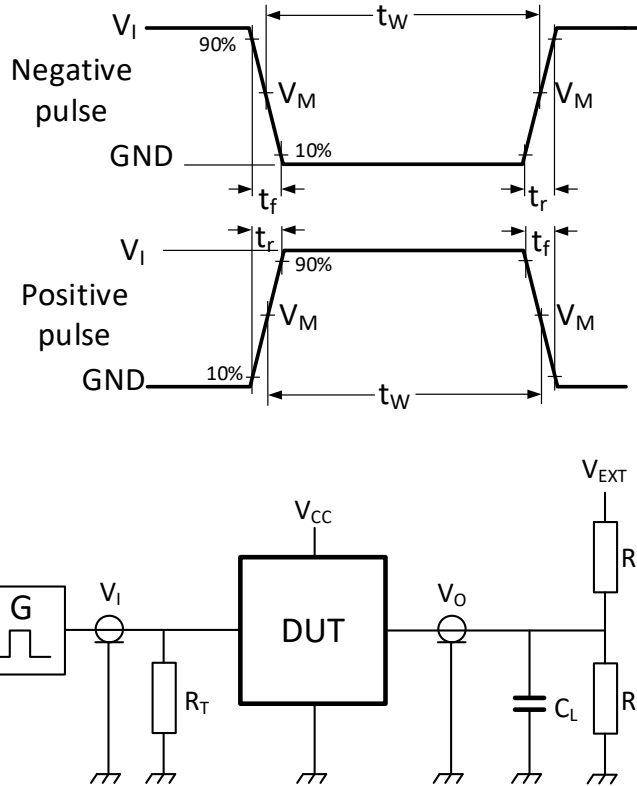
Fig. 5. 3-state enable and disable times

Table 8. Measurement points

Type	Input	Output		
	V_M	V_M	V_X	V_Y
EM74HCS245	$0.5V_{CC}$	$0.5V_{CC}$	$0.1V_{CC}$	$0.9V_{CC}$

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Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 6. Test circuit for measuring switching times

Table 9. Test data

Type	Input		Load		V_{EXT}		
	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
EM74HCS245	V_{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	$2V_{CC}$

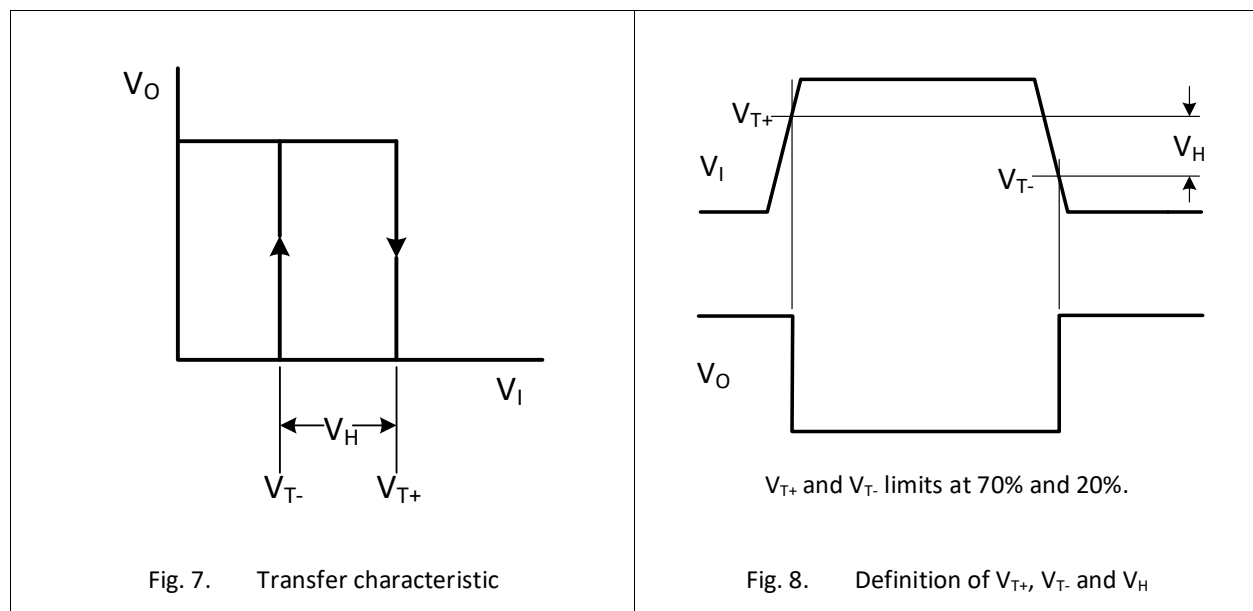
11. Transfer Characteristics

Table 10. Transfer characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V). Typical values are measured at $T_{amb} = 25^{\circ}\text{C}$.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
V_{T+}	positive-going threshold voltage	see Fig. 7 and Fig. 8						
		$V_{CC} = 2.0\text{ V}$	0.7	1.21	1.5	0.7	1.5	V
		$V_{CC} = 4.5\text{ V}$	1.7	2.39	3.15	1.7	3.15	V
		$V_{CC} = 6.0\text{ V}$	2.1	3.05	4.2	2.1	4.2	V
V_{T-}	negative-going threshold voltage	see Fig. 7 and Fig. 8						
		$V_{CC} = 2.0\text{ V}$	0.3	0.6	1.0	0.3	1.0	V
		$V_{CC} = 4.5\text{ V}$	0.9	1.41	2.2	0.9	2.2	V
		$V_{CC} = 6.0\text{ V}$	1.2	1.9	3.0	1.2	3.0	V
V_H	hysteresis voltage	see Fig. 7 and Fig. 8						
		$V_{CC} = 2.0\text{ V}$	0.2	0.61	1.0	0.2	1.0	V
		$V_{CC} = 4.5\text{ V}$	0.4	0.97	1.4	0.4	1.4	V
		$V_{CC} = 6.0\text{ V}$	0.6	1.16	1.6	0.6	1.6	V

11.1. Waveforms transfer characteristics

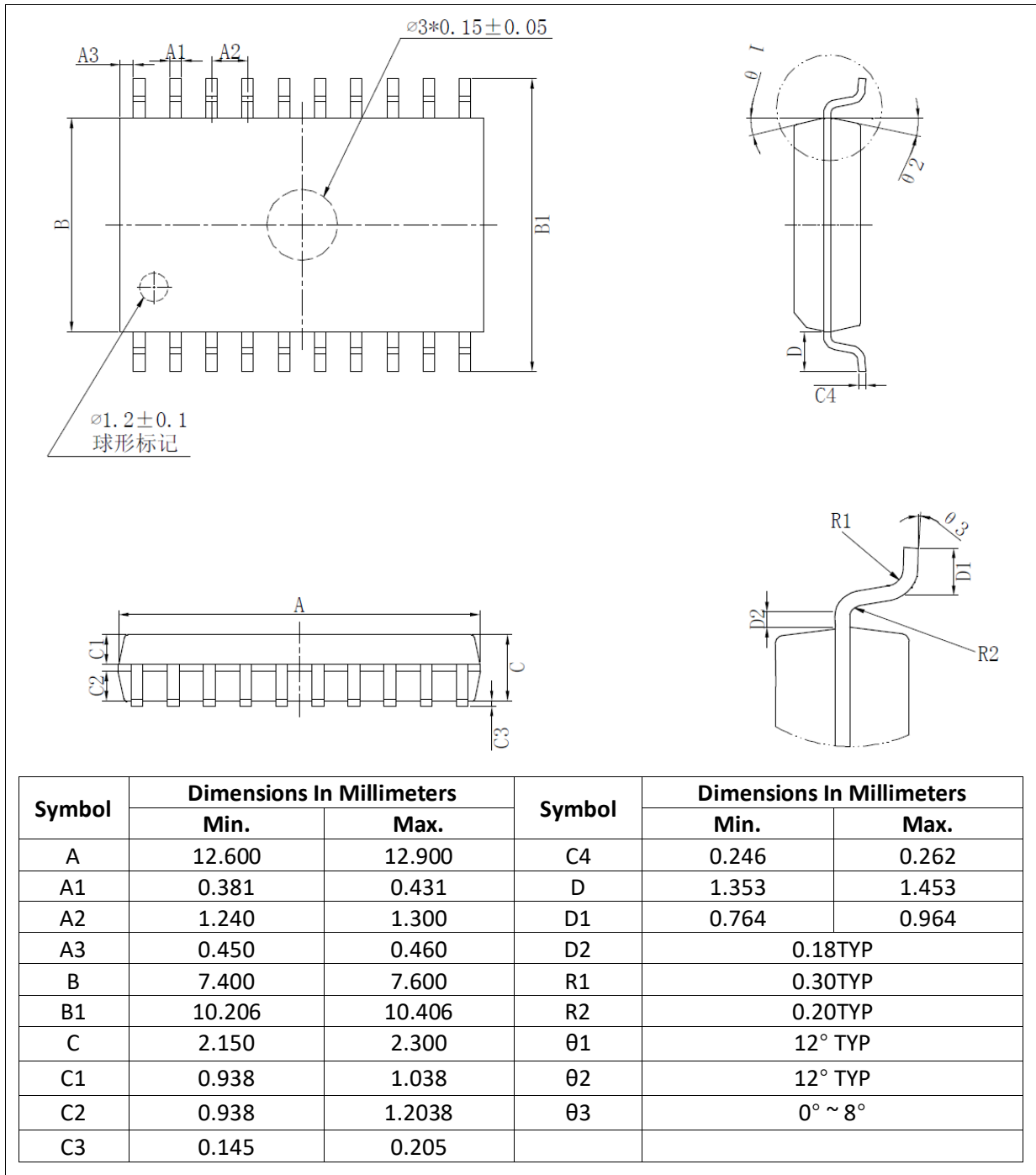


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12. Package Outline

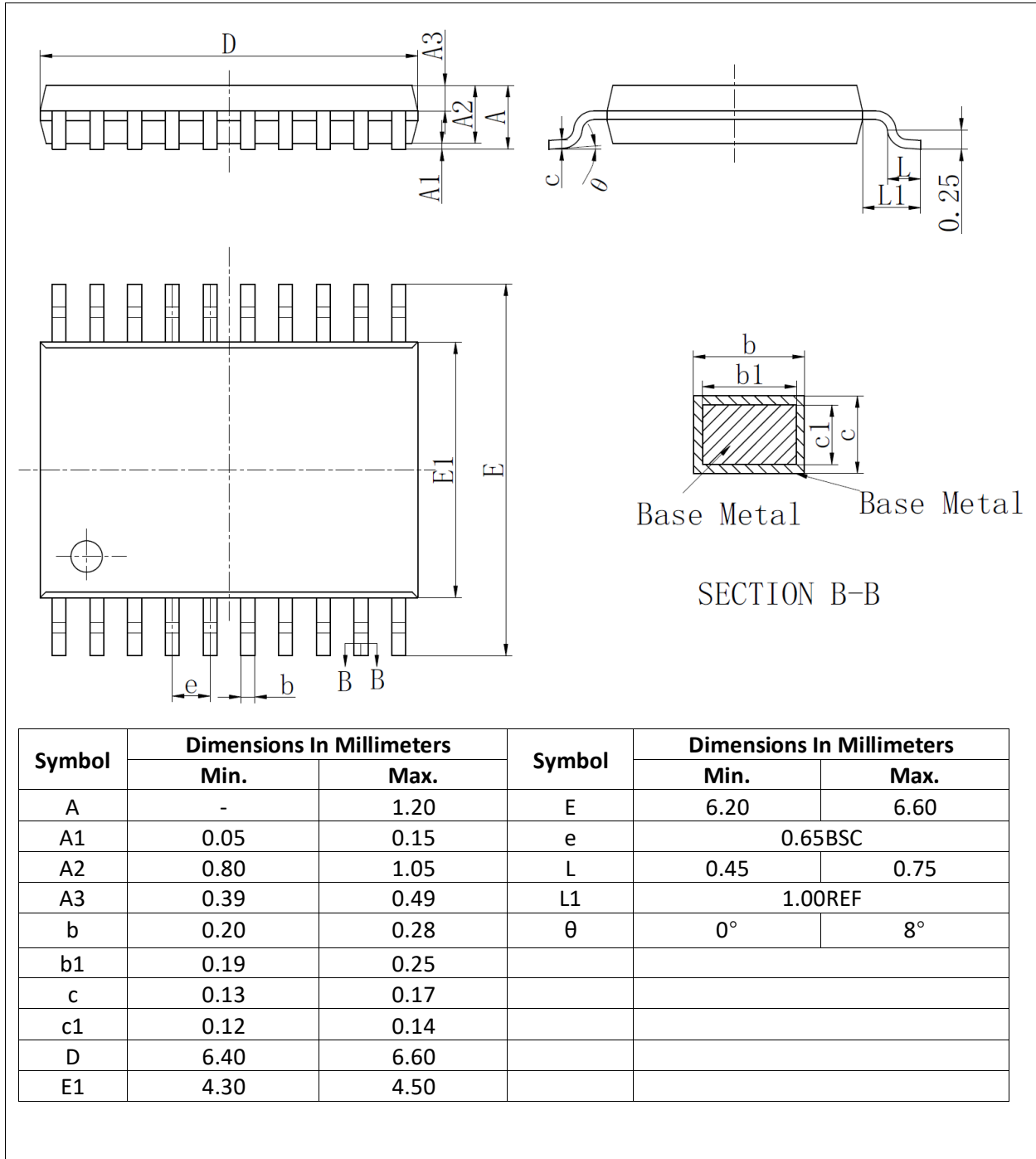
SOP-20L



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TSSOP-20L



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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
CDM	Charged Device Model

14. Revision History

Table 12. Revision history

Document ID	Release Date	Data sheet status	Change notice	Supersedes
EM74HCS245 Rev. 0.9	Feb 18, 2025	Draft datasheet		